

### **Product Summary**

Applications

**DC-DC Converters** 

**Power Management Functions** 

Battery Operated Systems and Solid-State Relays

V <sub>(BR)DSS</sub>	R <sub>DS(on)</sub>	Ι <sub>D</sub> T <sub>A</sub> = +25°C
	52mΩ @ V <sub>GS</sub> = 10V	4A
30V	65mΩ @ V <sub>GS</sub> = 4.5V	3A
	85mΩ @ V <sub>GS</sub> = 2.5V	2A

#### Features

- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e.: parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please refer to the related automotive grade (Q-suffix) part. A listing can be found at

https://www.diodes.com/products/automotive/automotiveproducts/.

This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability.

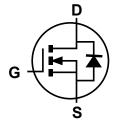
https://www.diodes.com/quality/product-definitions/

#### **Mechanical Data**

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208 3
- Terminal Connections: See Diagram
- Weight: 0.008 grams (approximate)

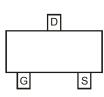


Top View



SOT23

Equivalent Circuit



Pin Configuration

### Ordering Information (Note 4)

Part Number	Case	Packaging
DMG3402L-7	SOT23	3000/Tape & Reel
DMG3402L-13	SOT23	10000/Tape & Reel

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. 2. See https://www.diodes.com/guality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and

Lead-free.
Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and</li>

8. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.</p>

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

sistance



## **Marking Information**



N32 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: I = 2021) M = Month (ex: 9 = September)

Date Code Key

	2040		2024	2022	0000	0004	2025	2022	0007	0000	0000	0000
Year	2012		2021	2022	2023	2024	2025	2026	2027	2028	2029	2030
Code	Z		Ι	J	K	L	М	N	0	Р	R	S
								A	San	Oct	Nev	Dee
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec

### Maximum Ratings (@ T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Drain Source Voltage	V <sub>DSS</sub>	30	V
Gate-Source Voltage	V <sub>GSS</sub>	±12	V
Drain Current (Note 5)	Ι <sub>D</sub>	4.0	А
Body-Diode Continuous Current (Note 5)	I <sub>S</sub>	1.5	A

## **Thermal Characteristics**

Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 5)	PD	1.4	W
Thermal Resistance, Junction to Ambient $@T_A = +25^{\circ}C$ (Note 5)	R <sub>θJA</sub>	90	°C/W
Operating and Storage Temperature Range	T <sub>J,</sub> T <sub>STG</sub>	-55 to +150	°C



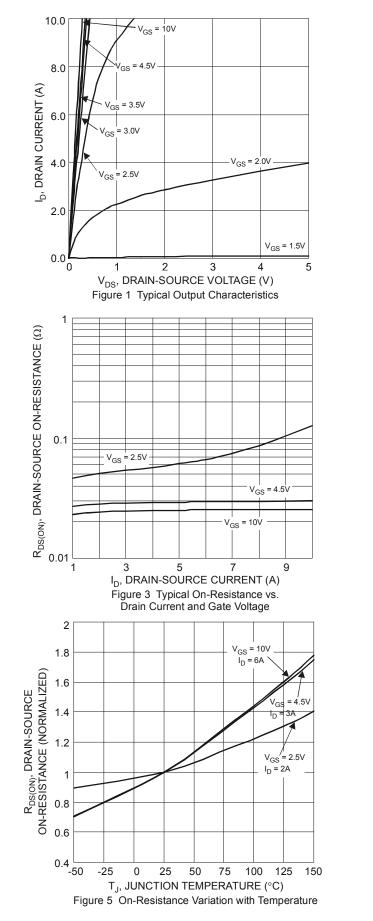
# Electrical Characteristics (@ T<sub>A</sub> = +25°C, unless otherwise specified.)

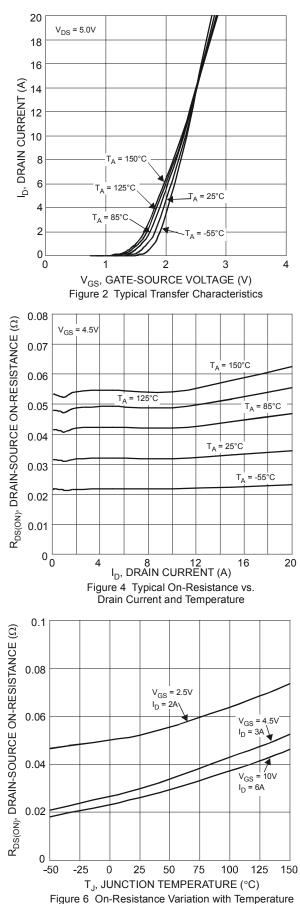
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 6)	I I					•	
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	30	_	_	V	V <sub>GS</sub> = 0V, I <sub>D</sub> = 250µA	
Zero Gate Voltage Drain Current	IDSS	_	_	1	μA	V <sub>DS</sub> = 30V, V <sub>GS</sub> = 0V	
Gate-Body Leakage	Igss			±100	nA	$V_{GS} = \pm 12V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 6)						•	
Gate Threshold Voltage	V <sub>GS(th)</sub>	0.6	_	1.4	V	$V_{DS}$ = $V_{GS}$ , $I_D$ = 250 $\mu$ A	
			_	52		V <sub>GS</sub> = 10V, I <sub>D</sub> = 4A	
Static Drain-Source On-Resistance	R <sub>DS(on)</sub>	_	—	65	mΩ	$V_{GS}$ = 4.5V, $I_{D}$ = 3A	
			—	85		$V_{GS}$ = 2.5V, $I_{D}$ = 2A	
Forward Transconductance	Y <sub>fs</sub>	_	6.6		S	V <sub>DS</sub> = 5V, I <sub>D</sub> = 3.1A	
Source-Drain Diode Forward Voltage	V <sub>SD</sub>			1.16	V	V <sub>GS</sub> = 0V, I <sub>S</sub> = 2.0A	
DYNAMIC CHARACTERISTICS(Note 7)							
Gate Resistance	R <sub>g</sub>		2.2	_	Ω	$V_{DS}$ =0V, $V_{GS}$ = 0V, f = 1MHz	
Total Gate Charge (10V)	Qg	_	11.7	_	nC	V <sub>GS</sub> = 10 V, V <sub>DS</sub> = 15V, I <sub>D</sub> = 4 A	
Total Gate Charge (4.5V)	Qg	_	5.5		nC		
Gate-Source Charge	Q <sub>gs</sub>	_	1.1		nC	V <sub>GS</sub> =10 V, V <sub>DS</sub> = 15V,	
Gate-Drain Charge	Q <sub>gd</sub>		1.8		nC	$I_D = 4 A$	
Turn-On Delay Time	t <sub>D(on)</sub>	_	1.9		ns		
Turn-On Rise Time	tr	_	1.6	_	ns	V <sub>DD</sub> = 15V, V <sub>GEN</sub> = 10V,	
Turn-Off Delay Time	t <sub>D(off)</sub>	_	10.3		ns	$R_{GEN}$ =3Ω, $R_L$ = 3.75Ω	
Turn-Off Fall Time	()		2.0		ns	1	
Input Capacitance	C <sub>iss</sub>		464	_	pF		
Output Capacitance	C <sub>oss</sub>		49.5	_	pF	$V_{DS} = 15V, V_{GS} = 0V$	
Reverse Transfer Capacitance	C <sub>rss</sub>	_	43.8	_	pF	f = 1.0MHz	

Notes: 5. Device mounted on FR-4 PCB. t  $\leq$ 5 sec.

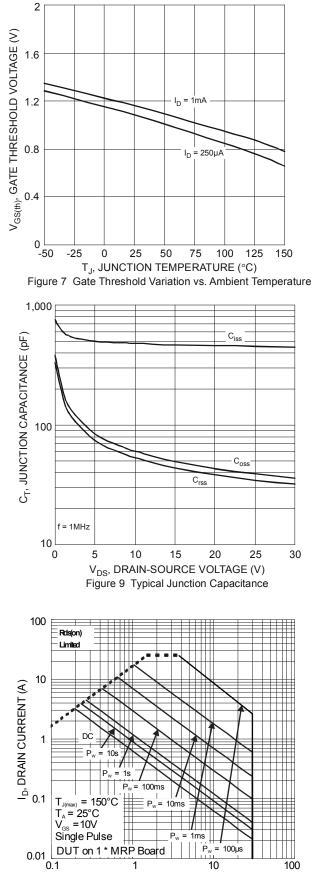
6. Short duration pulse test used to minimize self-heating effect.
7. Guaranteed by design. Not subject to production testing.

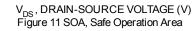


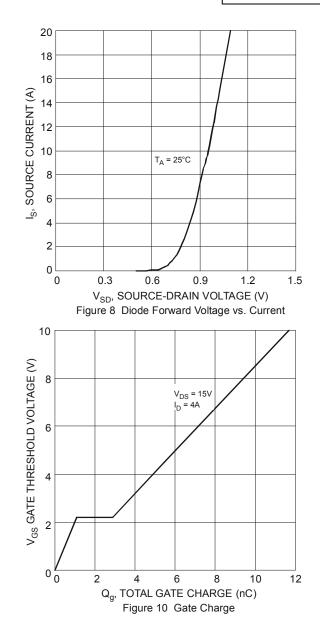




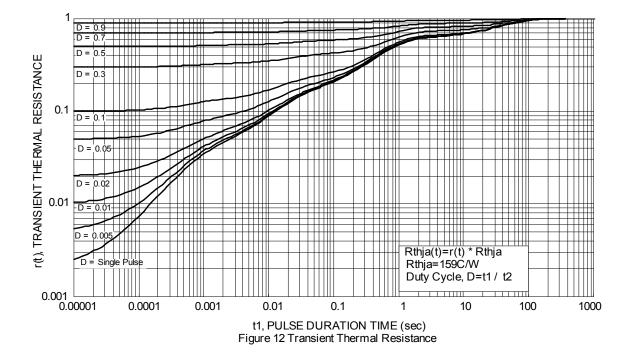








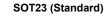


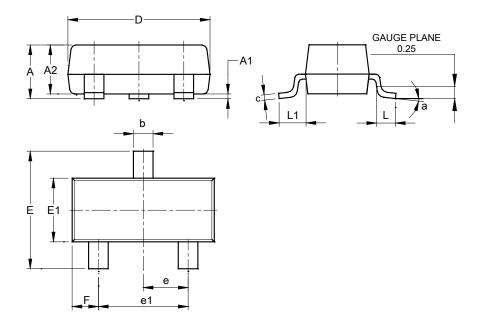




# **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.



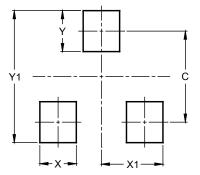


SOT23 (Standard)							
Dim	Min	Max	Тур				
Α	0.90	1.15	1.025				
A1	0.00	0.10	0.05				
A2	0.85	1.10	0.975				
b	0.30	0.51	0.40				
С	0.080	0.202	0.11				
D	2.80	3.00	2.90				
Е	2.25	2.55	2.40				
E1	1.20	1.40	1.30				
е	0.89	1.03	0.915				
e1	1.78	2.05	1.83				
F	0.40	0.60	0.535				
L1	0.45	0.61	0.55				
L	0.25	0.55	0.40				
а	0°	8°					
All Dimensions in mm							

## **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### SOT23 (Standard)



Dimensions	Value (in mm)
С	2.0
Х	0.8
X1	1.35
Y	0.9
Y1	2.9



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